

1N4148 / 1N4448

150mA Axial Leaded Fast Switching Diode

Features

- Fast Switching Speed
- General Purpose Rectification
- Silicon Epitaxial Planar Construction

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Mechanical Data

Case: DO-35

Leads: Solderable per MIL-STD-202,

Method 208

Polarity: Cathode BandMarking: Type Number

Weight: 0.13 grams (approx.)

DO-35						
Dim	Min	Max				
Α	25.40	_				
В	_	4.00				
С	_	0.60				
D	_	2.00				
All Dimensions in mm						

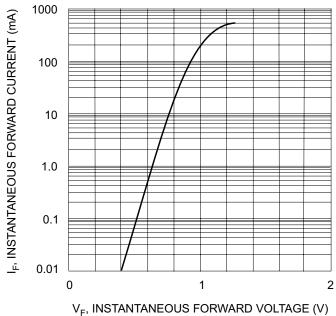
Maximum Ratings and Electrical Characteristics @

@ $T_A = 25$ °C unless otherwise specified

Characteristic		Symbo	ol		1N4148	1N	4448	Unit	
Non-Repetitive Peak Reverse Voltage		V _{RM}			100			V	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R		75			V		
RMS Reverse Voltage		V _{R(RMS)}		53				V	
Forward Continuous Current (Note 1)		I _{FM}			300	5	600	mA	
Average Rectified Output Current (Note 1)		Io			150		mA		
Non-Repetitive Peak Forward Surge Current @ $t = 1.0s$ @ $t = 1.0\mu s$		I _{FSM}			1.0 2.0		А		
Power Dissipation (Note 1) Derate Above 25°C		P _d		500 1.68			mW mW/°C		
Thermal Resistance, Junction to Ambient Air (Note 1)		$R_{ heta JA}$		300			K/W		
Operating and Storage Temperature Range		T _j , T _{STG}		-65 to +175			°C		
Characteristic		Symbol	Min	1	Max Unit		Те	Test Condition	
Maximum Forward Voltage	1N4148 1N4448 1N4448	V _{FM}	0.62 —	2	1.0 0.72 1.0	V	I _F = 10mA I _F = 5.0mA I _F = 100mA		
Maximum Peak Reverse Current		I _{RM}	_		5.0 50 30 25	μΑ μΑ μΑ nA	$\begin{tabular}{lll} $V_R = 75V$ \\ $V_R = 70V, \ T_j = 150^{\circ}C$ \\ $V_R = 20V, \ T_j = 150^{\circ}C$ \\ $V_R = 20V$ \\ \end{tabular}$		
Capacitance		Cj	_		4.0	pF	$V_R = 0, f = 1.0MHz$		
Reverse Recovery Time		t _{rr}	_		4.0	ns	I_F = 10mA to I_R =1.0mA V_R = 6.0V, R_L = 100 Ω		

Notes: 1. Valid provided that device terminals are kept at ambient temperature.





10,000 100 PAKAGE CURRENT (nA) 100 PAKAGE CURRENT (nA)

V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 1 Forward Characteristics

 T_{j} , JUNCTION TEMPERATURE (°C) Fig. 2, Leakage Current vs Junction Temperature